

DN74LS51 *DN74LS51*

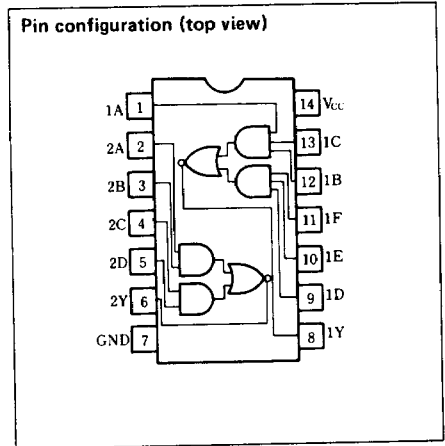
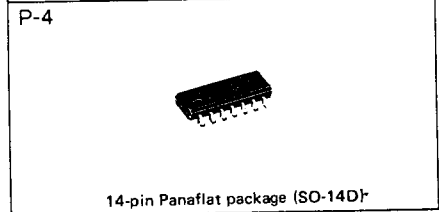
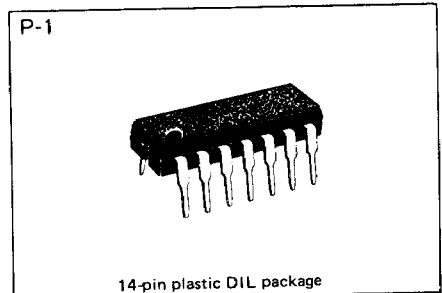
2-wide 3-input, 2-wide 2-input AND-OR-INVERT Gates

■ **Description**

DN74LS51 contains two 2-input and two 3-input AND-OR-INVERT gates.

■ **Features**

- Low power consumption ($P_d = 5.5\text{mW}$ typical)
- High speed ($t_{pd} = 12\text{ns}$ typical)
- Low output impedance
- Wide operating temperature range ($T_a = -20$ to $+75^\circ\text{C}$)



■ **Recommended operating conditions**

Parameter	Sym	Min	Typ	Max	Unit
Supply voltage	V_{CC}	4.75	5.00	5.25	V
Output current	I_{OH}			-400	μA
	I_{OL}			8	mA
Operating temperature range	T_{opr}	-20	25	75	$^\circ\text{C}$

4.2

12P

■ DC characteristics (Ta = -20 ~ +75°C)

Parameter	Sym	Test conditions	Min	Typ*	Max	Unit	
Input voltage	V _{IH}		2.0			V	
	V _{IL}				0.8	V	
Output voltage	V _{OH}	V _{CC} = 4.75V, V _{IL} = 0.8V I _{OH} = -400 μA	2.7	3.4		V	
	V _{OL1}	V _{CC} = 4.75V		0.25	0.4	V	
	V _{OL2}	V _{IH} = 2V	I _{OL} = 4mA		0.35	0.5	V
			I _{OL} = 8mA				
Input current	I _{IH}	V _{CC} = 5.25V V _I = 2.7V			20	μA	
	I _{IL}	V _{CC} = 5.25V V _I = 0.4V			-0.4	mA	
	I _I	V _{CC} = 5.25V V _I = 7V			0.1	mA	
Output short circuit current**	I _{OS}	V _{CC} = 5.25V, V _O = 0V	-15		-100	mA	
Input clamp voltage	V _{IK}	V _{CC} = 4.75V I _I = -18mA			-1.5	V	
Supply current	I _{CCH}	V _{CC} = 5.25V,		0.8	1.6	mA	
	I _{CCL}	V _{CC} = 5.25V,		1.4	2.8	mA	

* When constant at V_{CC} = 5V, Ta = 25°C.

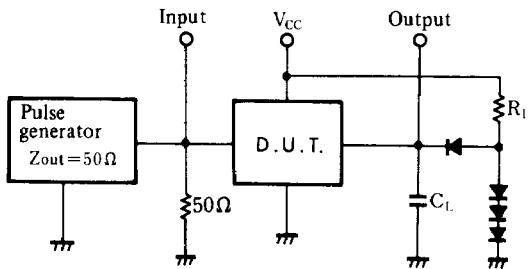
** Only one output at a time short circuited to GND. Also, short circuit time to GND within 1 second.

■ Switching characteristics (V_{CC} = 5V, Ta = 25°C)

Parameter	Sym	Test conditions	Min	Typ	Max	Unit
Propagation delay time	t _{PLH}	C _L = 15pF, R _L = 2kΩ		12	20	ns
	t _{PHL}			12.5	20	ns

※ Switching parameter measurement information

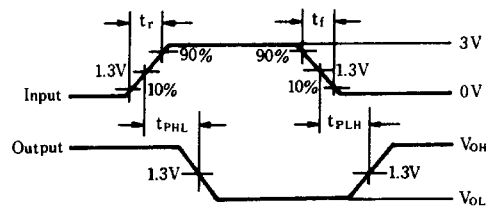
1. Measurement circuit



Notes

1. C_L includes probe and tool floating capacitance.
2. Diodes are all MA161 or equivalent.

2. Waveforms



Notes

1. Input waveform: t_r ≤ 15ns, t_f ≤ 6ns, PRR = 1MHz, duty cycle = 50%.